Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RQK0607AQDQS

Silicon N Channel MOS FET Power Switching

REJ03G1620-0100 Rev.1.00 Mar 03, 2008

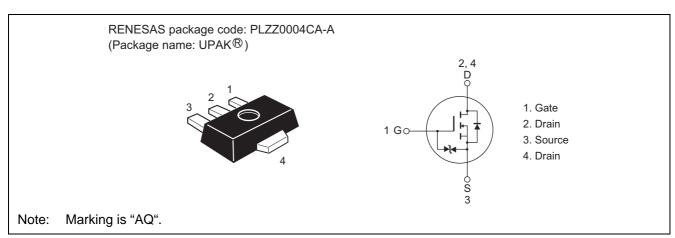
Features

• Low on-resistance

 $R_{DS(on)} = 210 \text{ m}\Omega \text{ typ.} (\text{at } V_{GS} = 4.5 \text{ V}, I_D = 1.2 \text{ A})$

- Low drive current
- High speed switching
- \bullet V_{DSS}: 60 V and capable of 2.5 V gate drive

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

			()
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V_{GSS}	±12	V
Drain current	I _D	2.4	А
Drain peak current	I _{D(pulse)} Note1	8	А
Body - drain diode reverse drain current	I _{DR}	2.4	А
Channel dissipation	Pch Note2	1.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. When using the glass epoxy board (FR-4 $40\times40\times1$ mm)

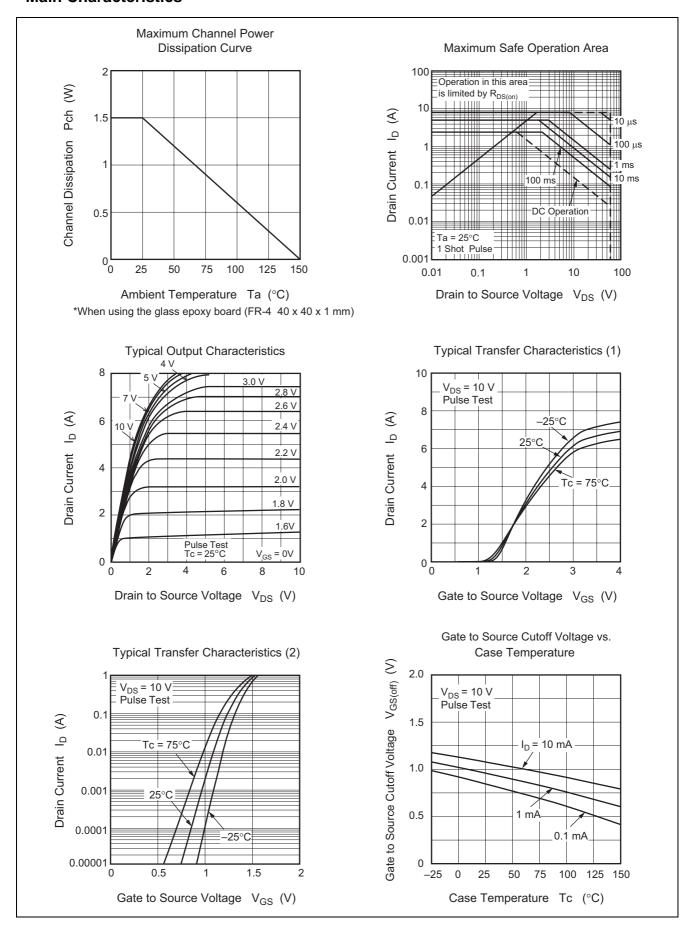
Electrical Characteristics

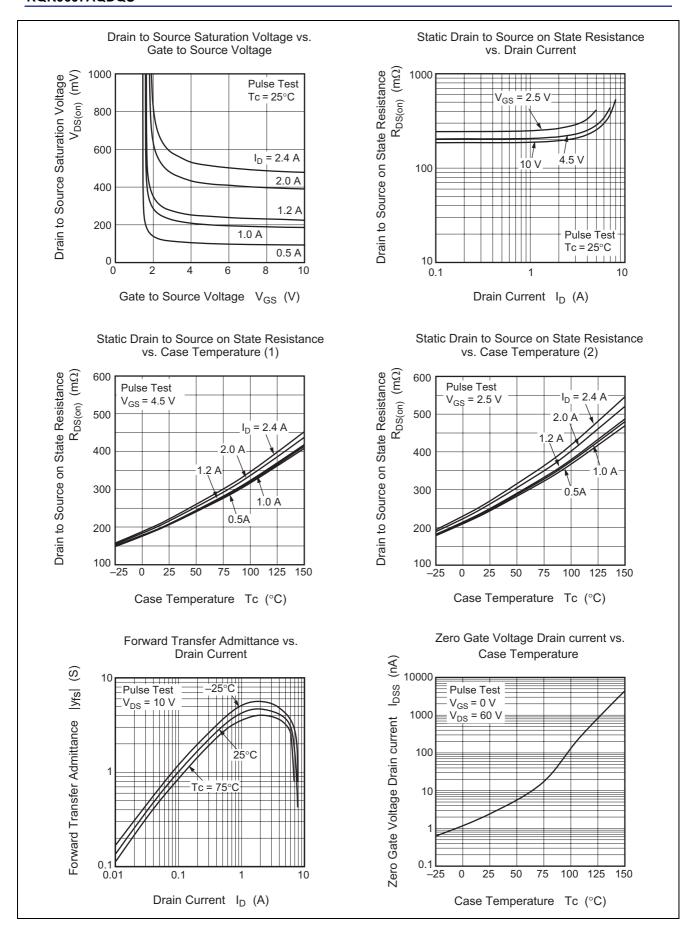
 $(Ta = 25^{\circ}C)$

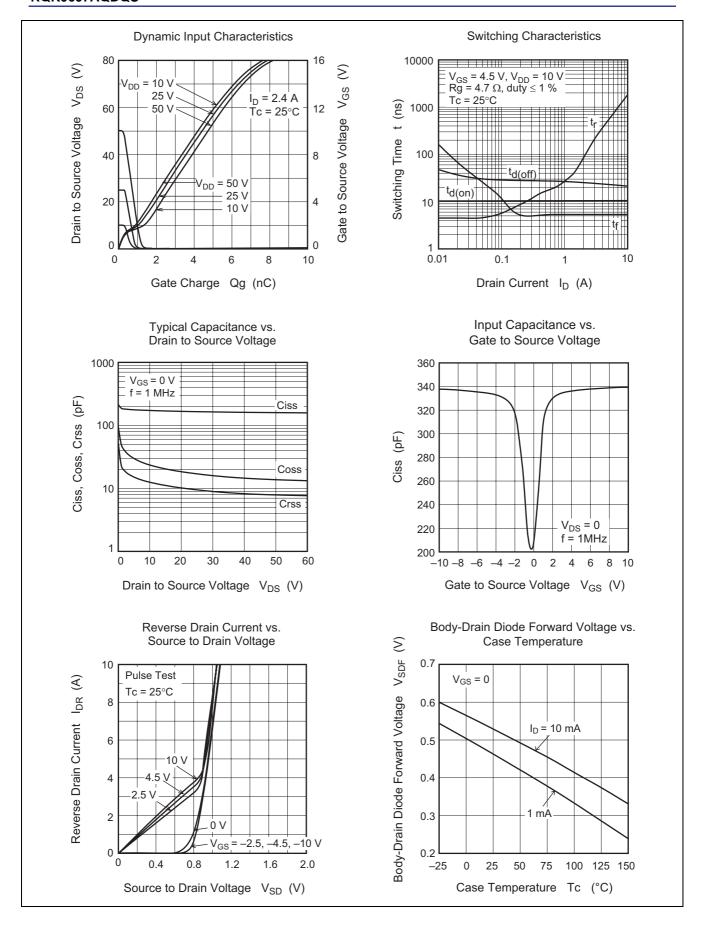
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	+12	_	_	V	$I_G = +100 \mu A, V_{DS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	-12	_	_	V	$I_G = -100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	+10	μΑ	$V_{GS} = +10 \text{ V}, V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	-10	μΑ	$V_{GS} = -10 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}		_	1	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	0.4	_	1.4	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Drain to source on state resistance	R _{DS(on)}	_	210	270	mΩ	$I_D = 1.2 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note3}}$
Drain to source on state resistance	R _{DS(on)}	_	250	350	mΩ	$I_D = 1.2 \text{ A}, V_{GS} = 2.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	y _{fs}	2.8	4.4	_	S	$I_D = 1.2 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note3}}$
Input capacitance	Ciss	_	170	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	24	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	11	_	pF	f = 1 MHz
Turn - on delay time	t _{d(on)}	_	10	_	ns	I _D = 1.2 A
Rise time	t _r	_	33	_	ns	$V_{GS} = 4.5 \text{ V}$
Turn - off delay time	t _{d(off)}	_	26	_	ns	$R_L = 8.3 \Omega$
Fall time	t _f	_	5	_	ns	$Rg = 4.7 \Omega$
Total gate charge	Qg	_	2	_	nC	V _{DD} = 10 V
Gate to Source charge	Qgs	_	0.4	_	nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	Qgd	_	0.5	_	nC	I _D = 2.4 A
Body - drain diode forward voltage	V_{DF}	_	0.8	_	V	$I_F = 2.4 \text{ A}, V_{GS} = 0^{\text{Note3}}$

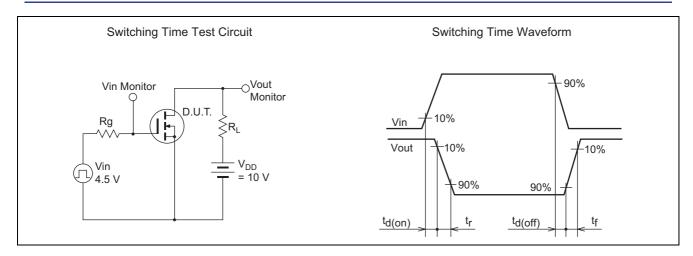
Notes: 3. Pulse test

Main Characteristics

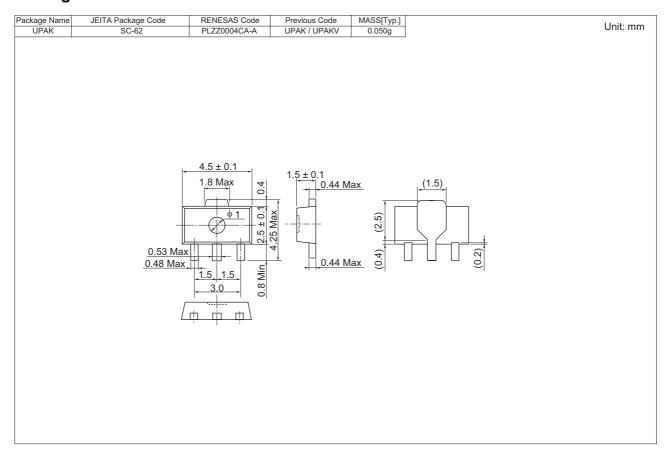








Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RQK0607AQDQSTL-E	1000 pcs.	φ178 mm reel, 12 mm Emboss taping

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